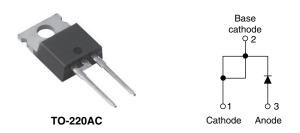
VS-18TQ0..PbF Series, VS-18TQ0..-N3 Series

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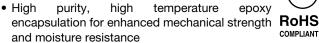
High Performance Schottky Rectifier, 18 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	18 A				
V_{R}	35 V, 40 V, 45 V				
V _F at I _F	0.53 V				
I _{RM} max.	25 mA at 125 °C				
T _J max.	175 °C				
E _{AS}	24 mJ				
Package	TO-220AC				
Circuit configuration	Single				

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation





- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-18TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	18	Α				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	t _p = 5 μs sine	1800	Α				
V _F	18 A _{pk} , T _J = 125 °C	0.53	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-18TQ035PbF VS-18TQ040PbF VS-18TQ045PbF VS-18TQ035-N3 VS-18TQ040-N3 VS-18TQ045-N3 UNITS						
Maximum DC reverse voltage	V_R	35	40	45	V	
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 149 °C	18			
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse Following any rated load		1800	Α	
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	390		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3.6 A, L = 3.7 mH		24	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	Α	



VS-18TQ0..PbF Series, VS-18TQ0..-N3 Series

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
Maximum forward voltage drop See fig. 1		18 A	T 05 00	0.60	V	
	V _{EM} (1)	36 A	T _J = 25 °C	0.72		
	V _{FM} (')	18 A	T 105 °C	0.53		
		36 A	T _J = 125 °C	0.67		
Maximum reverse leakage current	ı (1)	T _J = 25 °C	V _R = Rated V _R	2.5	mA	
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	v _R = nateu v _R	25	IIIA	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +175	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.50	°C/W		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased 0.50		G/W		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
minimum			6 (5)	kgf · cm		
Mounting torque maximum			12 (10)	(lbf ⟨ in)		
		Case style TO-220AC		2035		
Marking device				2040		
			18TC	Q045		

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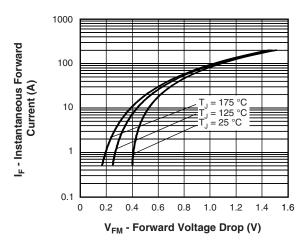


Fig. 1 - Maximum Forward Voltage Drop Characteristics

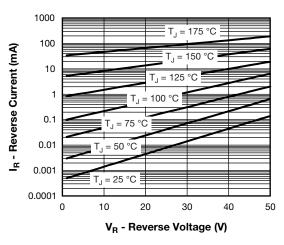


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

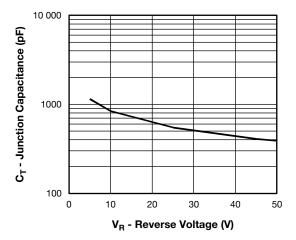


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

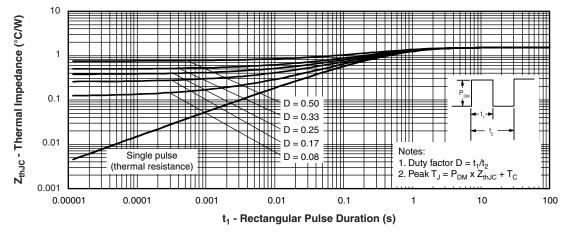


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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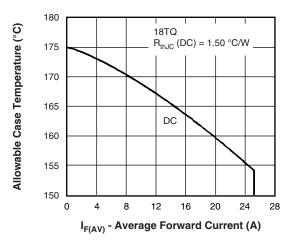


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

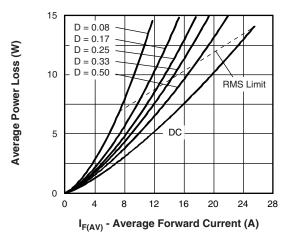


Fig. 6 - Forward Power Loss Characteristics

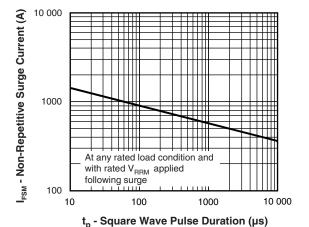


Fig. 7 - Maximum Non-Repetitive Surge Current

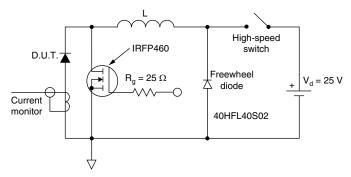


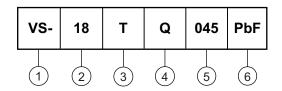
Fig. 8 - Unclamped Inductive Test Circuit

VS-18TQ0..PbF Series, VS-18TQ0..-N3 Series

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (18 = 18 A)

3 - Package:

T = TO-220

4 - Schottky "Q" series

035 = 35 V 040 = 40 V

5 - Voltage ratings

045 = 45 V

6 - Environmental digit

• PbF = lead (Pb)-free and RoHS-compliant

• -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-18TQ035PbF	50	1000	Antistatic plastic tube			
VS-18TQ035-N3	50	1000	Antistatic plastic tube			
VS-18TQ040PbF	50	1000	Antistatic plastic tube			
VS-18TQ040-N3	50	1000	Antistatic plastic tube			
VS-18TQ045PbF	50	1000	Antistatic plastic tube			
VS-18TQ045-N3	50	1000	Antistatic plastic tube			

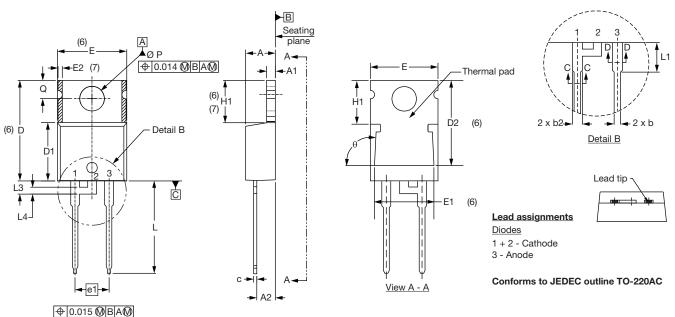
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95221</u>					
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224			
	TO-220AC -N3	www.vishay.com/doc?95068			
SPICE model		www.vishay.com/doc?96209			



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES	
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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